

# High-reliability discrete products and engineering services since 1977

# MCR70, MCR71 SERIES

### SILICON CONTROLLED RECTIFIERS

### **FEATURES**

- Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.
- Available as non-RoHS (Sn/Pb plating), standard, and as RoHS by adding "-PBF" suffix.

### **MAXIMUM RATINGS**

Rating		Combat	Value		
		Symbol	MCR70	MCR71	Unit
Repetitive peak forward or reverse blocking voltage (1)  MCR70  MCR71	1 2 3	$V_{ m DRM}/V_{ m RRM}$	5	25 50 00	Volts
Peak discharge current (2)		I <sub>TM</sub>	850	1700	Amps
On-state current (T <sub>C</sub> ≤ 75°C)		I <sub>T(RMS)</sub> I <sub>T(AV)</sub>	35 22	55 35	Amps
Peak non-repetitive surge current (1/2 cycle, sine wave, 60Hz, T <sub>J</sub> = 125°C)		I <sub>TSM</sub>	350	550	Amps
Circuit fusing (t = 8.3 ms)		l <sup>2</sup> t	510	1255	A <sup>2</sup> s
Critical rate of rise of current (3)		di/dt	100	200	A/μs
Forward peak gate power (t ≤ 20µs)		$P_{GM}$	2	20	
Forward average gate power		$P_{G(AV)}$	C	0.5	
Forward peak gate current ( $t \le 20 \mu s$ )		I <sub>GM</sub>		2	
Operating junction storage temperature range		Tı	-40 to	-40 to +125	
Storage temperature range		$T_{stg}$	-40 to	-40 to +150	
Mounting torque		-	3	30	

The rated voltage can be applied over the rated operating junction temperatures without incurring damage. Ratings apply for shorted-open or shorted-gate conditions or negative voltage on the gate. Devices should not be tested for blocking capability in a manner such that the voltage supplied exceeds the rated blocking voltages.

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal resistance, junction to case	R <sub>eJC</sub>	1	°C/W

### **ELECTRICAL CHARACTERISTICS** (T<sub>1</sub> = 25°C unless otherwise specified)

Characteristic		Symbol	Min	Тур	Max	Unit
Peak forward or reverse blocking current (	rated V <sub>DRM</sub> or V <sub>RRM</sub> )					
(T <sub>J</sub> = 25°C)		I <sub>DRM</sub> , I <sub>RRM</sub>	-	-	10	μΑ
(T <sub>J</sub> = 125°C)			-	-	2	mA
On-state voltage (1)						
(I <sub>TM</sub> = 70A)	MCR70 SERIES		-	1.5	1.85	
$(I_{TM} = 175A)$	MCR71 SERIES	$V_{TM}$	-	1.7	2.1	Volts
$(I_{TM} = 850A, t_w = 1ms)^{(2)}$	MCR70 SERIES		-	6	-	
$(I_{TM} = 1700A, t_w = 1ms)^{(2)}$	MCR71 SERIES		-	7	-	
Gate trigger current (continuous dc) $(V_D = 12V, R_L = 100\Omega)$		I <sub>GT</sub>	2	10	30	mA

Rating is for  $t_w$  = 1ms. Test conditions:  $I_G$  = 150mA,  $V_D$  = Rated  $V_{DRM}$ ,  $I_{TM}$  = Rated value,  $T_J$  = 125°C.



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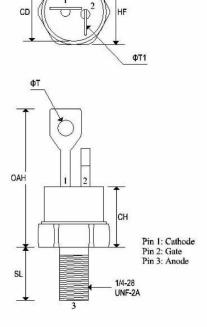
Gate trigger voltage (continuous dc)					
$(V_D = 12V, R_L = 100\Omega)$	$V_{GT}$	-	1	1.5	Volts
$(V_D = rated V_{DRM}, R_L = 1k\Omega, T_J = 125^{\circ}C)$		0.2	-	-	
Holding current (I <sub>TM</sub> = 0.5A, gate open)	I <sub>H</sub>	3	15	50	mA
Latching current ( $V_D = 12Vdc$ , $I_G = 150mA$ , $t_r \le 50\mu s$ )	ΙL	-	30	60	mA
Critical rate of rise off state voltage	dv/dt	10	-	-	V/µs
( $V_D$ = rated $V_{DRM}$ , gate open, exponential waveform, $T_C$ = 125°C)	uv/ut	10			
Turn on time <sup>(3)</sup>		t <sub>on</sub>			
$(V_D = rated V_{DRM}, I_G = 150mA)$					
(I <sub>TM</sub> = 70A, peak)	MCR70		-	1	μS
(I <sub>TM</sub> = 110A, peak)	SERIES		-	1.2	
	MCR71				
	SERIES				

#### Notes:

- Duty cycle  $\leq$  1%. Pulse width  $\leq$  300 $\mu$ s.
- Characteristic applies for  $t_w$  = 1ms.  $t_w$  is defined as 5 time constants of an exponentially decaying current pulse. The gate controlled turn-on time in a crowbar circuit will be influenced by the circuit inductance.

#### MECHANICAL CHARACTERISTICS

Case:	TO-48			
Marking:	Body painted, alpha-numeric			
Polarity:	Anode is stud			



	TO-48				
	Inches Millimeters			neters	
	Min	Max	Min	Max	
CD		0.543		13.793	
CH	·	0.550		13.970	
HF	0.544	0.563	13.817	14.301	
OAH	ī	1.193	-	30.303	
SL	0.422	0.453	10.718	11.507	
ΦТ	0.125	0.165	3.175	4.191	
ΦT <sub>1</sub>	0.060	0.075	1.524	1.905	

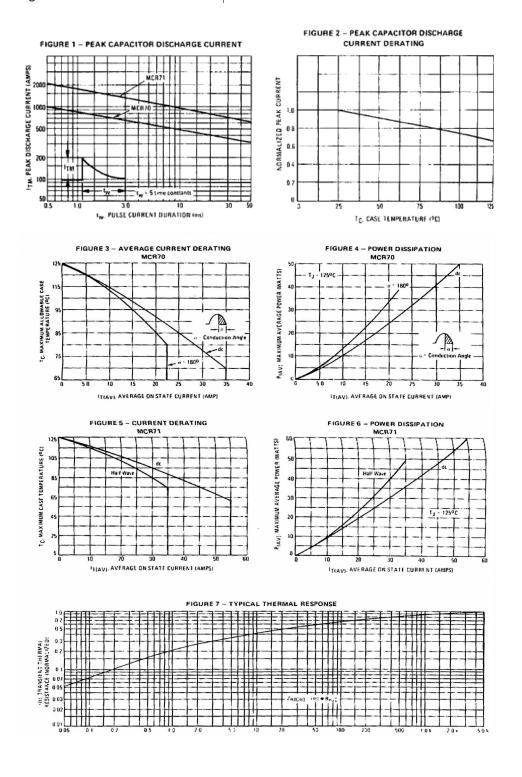
Note: Contour and angular orientation of terminals 1 and 2 with respect to hex portion and to each other are optional.



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